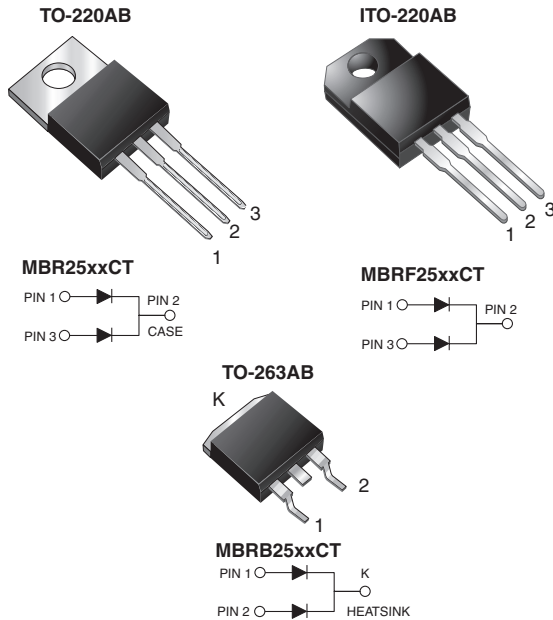


## Dual Common-Cathode Schottky Rectifier



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	15 A x 2
$V_{RRM}$	35 V to 60 V
$I_{FSM}$	150 A
$V_F$	0.73 V at 30 A, 0.65 V at 15 A
$T_J$ max.	150 °C

### MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	V
Working peak reverse voltage	$V_{RWM}$	35	45	50	60	
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	
Maximum average forward rectified current total device at $T_C = 130$ °C per diode	$I_{F(AV)}$	30 15				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	150				A
Peak repetitive reverse surge current per diode at $t_p = 2$ $\mu$ s, 1 kHz	$I_{RRM}$	1.0		0.5		
Peak non-repetitive reverse energy (8/20 $\mu$ s waveform) per diode	$E_{RSM}$	25				mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k $\Omega$	$V_C$	25				kV

# MBR(F,B)2535CT thru MBR(F,B)2560CT

Vishay General Semiconductor



MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000				V/μs
Operating junction temperature range	T <sub>J</sub>	- 65 to + 150				°C
Storage temperature range	T <sub>STG</sub>	- 65 to + 175				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V

ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 15 A	T <sub>C</sub> = 25 °C	-	-	0.75	V	
	I <sub>F</sub> = 15 A	T <sub>C</sub> = 125 °C	-	-	0.65		
	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25 °C	0.82	-	-		
	I <sub>F</sub> = 30 A	T <sub>C</sub> = 125 °C	0.73	-	-		
Maximum instantaneous reverse current at blocking voltage per diode <sup>(1)</sup>		T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	0.2 40		1.0 50	mA	

**Note:**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance from junction to case per diode	R <sub>θJC</sub>	1.5	4.5	1.5	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape reel
TO-220AB	MBR2545CTHE3/45 <sup>(1)</sup>	1.85	45	50/tube	Tube
ITO-220AB	MBRF2545CTHE3/45 <sup>(1)</sup>	1.99	45	50/tube	Tube
TO-263AB	MBRB2545CTHE3/45 <sup>(1)</sup>	1.35	45	50/tube	Tube
TO-263AB	MBRB2545CTHE3/81 <sup>(1)</sup>	1.35	81	800/reel	Tape reel

**Note:**

(1) Automotive grade AEC Q101 qualified



## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

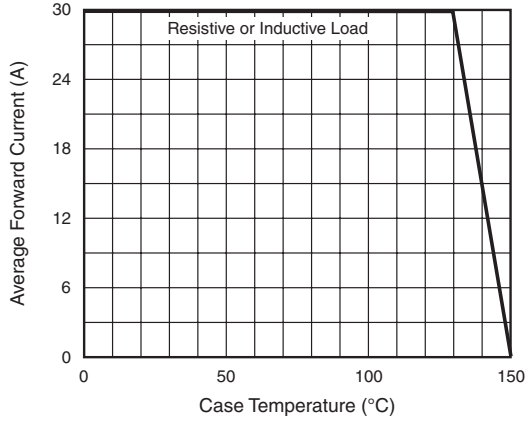


Figure 1. Forward Current Derating Curve

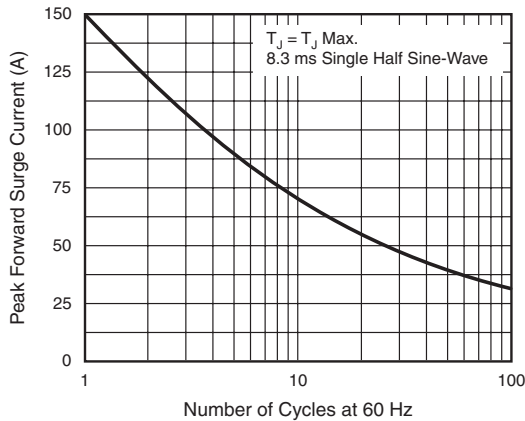


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

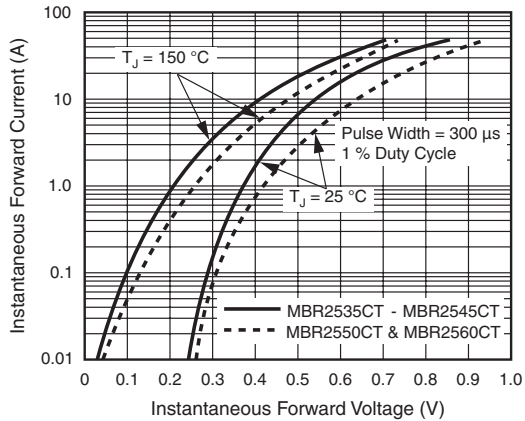


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

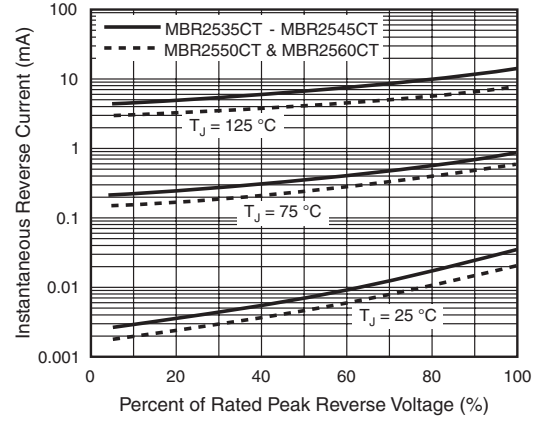


Figure 4. Typical Reverse Characteristics Per Diode

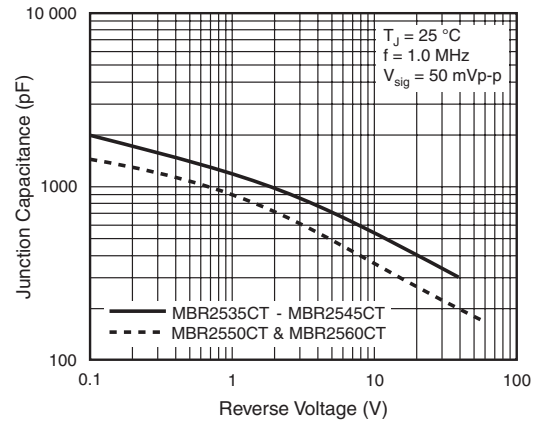


Figure 5. Typical Junction Capacitance Per Diode

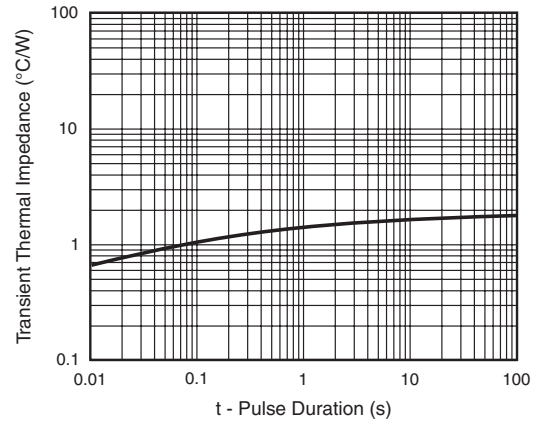


Figure 6. Typical Transient Thermal Impedance Per Diode





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